The documentation and process conversion measures necessary to comply with this shall be completed by 16 Aug 94.

INCH-POUND

MIL-S-19500/406C 16 May 1994 SUPERSEDING MIL-S-19500/406B 19 June 1992

#### MILITARY SPECIFICATION

SEMICONDUCTOR DEVICES, DIODE, SILICON, VOLTAGE REGULATOR
TYPES 1N4460, 1N4460C, 1N4460D THROUGH 1N4496, 1N4496C, 1N4496D AND
1N6485, 1N6485C, 1N6485D THROUGH 1N6491, 1N6491C, 1N6491D
1N4460US, 1N4460CUS, 1N4460DUS THROUGH 1N4496US, 1N4496CUS, 1N4496DUS AND
1N6485US, 1N6485CUS, 1N6485DUS THROUGH 1N6491US, 1N6491CUS, 1N6491DUS
PLUS C AND D TOLERANCE SUFFIX; JAN, JANTX, JANTXV, JANS, JANHC, AND JANKC

This specification is approved for use by all Departments and Agencies of the Department of Defense.

#### 1. SCOPE

- 1.1 <u>Scope</u>. This specification covers the detail requirements for microminiature 1.5 watt silicon, low leakage, voltage regulator diodes with tolerances of 5 percent, 2 percent, and 1 percent. Four levels of product assurance are provided for each device type as specified in MIL-S-19500, and two level of product assurance for die.
  - 1.2 Physical dimensions. See figures 1 (similar to DO-41), 2, and 3.
  - 1.3 Maximum ratings. Maximum ratings are as shown in columns 8 and 10 of table III herein and as follows:
    - $P_T$  = 1.5 W (derate at 10 mW/°C above  $T_A$  = +25°C) -55°C <  $T_{op}$  < +175°C; -65°C <  $T_{sto}$  < +175°C
- 1.4 Primary electrical characteristics. Primary electrical characteristics are as shown in columns 2, 9, 12, and 14 of table III herein and as follows:
  - 3.3 V dc  $\leq$  V<sub>z</sub>  $\leq$  200 V dc

1N4460D through 1N4496D and 1N6485D through 1N6491D are 1 percent voltage tolerance. 1N4460C through 1N4496C and 1N6485C through 1N6491C are 2 percent voltage tolerance. 1N4460 through 1N4496 and 1N6485 through 1N6491 are 5 percent voltage tolerance.

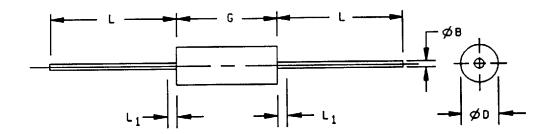
 $R_{\Theta JL} = 42^{\circ}C/W$  (max) at L = .375 inch (9.52 mm) (nonsurface mount)

 $R_{\Theta JEC} = 20^{\circ}C/W \text{ (max) (surface mount)}$ 

Beneficial comments (recommendations, additions, deletions) and any pertinent data which may be of use in improving this document should be addressed to: Defense Electronics Supply Center, DESC-ELD, 1507 Wilmington Pike, Dayton, OH 45444-5765 by using the Standardization Document Improvement Proposal (DD Form 1426) appearing at the end of this document or by letter.

AMSC N/A  $\underline{\text{DISTRIBUTION STATEMENT A}}$ . Approved for public release; distribution is unlimited.

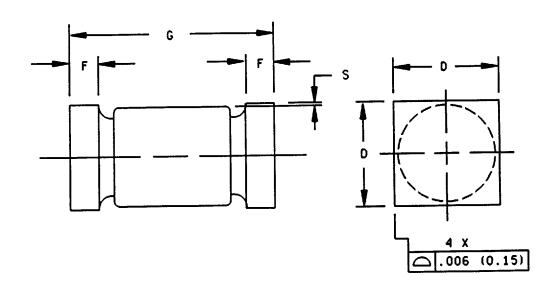
FSC 5961



Ltr		Notes			
	Inches		Millimeters		
	Min	Max	Min	Max	
G	.106	.160	2.69	4.06	3
φο	.060	.085	1.52	2.16	3
L	.800	1.300	20.32	33.02	
φВ	.028	.032	0.71	0.81	
L <sub>1</sub>		.050		1.27	4

- 1. Dimensions are in inches.
- Metric equivalents are given for general information only.
   Package contour optional with \$0 and length G. Heat slugs, if any, shall be included within this cylinder but shall not be subject to minimum limit of \$D.
- 4. The specified lead diameters apply in the zone between .050 inch (1.27 mm) from the diode body and the end of the lead.

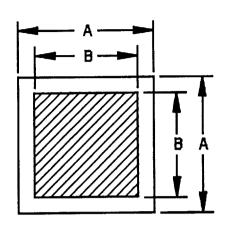
FIGURE 1. Physical dimensions of nonsurface mount device.

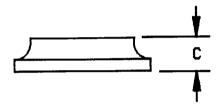


Ltr		Dimensions					
	Inches		Millimeters				
	Min	Max	Min	Max			
G	.168	.200	4.28	5.08			
F	.019	.028	0.48	0.71			
S	.003		0.08				
D	.091	.103	2,31	2.62			

- Dimensions are in inches.
   Metric equivalents are given for general information only.

FIGURE 2. Physical dimensions of surface mount device, "US".





Symbol	Dimension					
	Inch	es	Millimeters			
	Min	Max	Min	Max		
A	0.030	0.036	0.813	0.914		
В	0.022	0.027	0.584	0.686		
С	0.006	0.012	0.152	0.305		

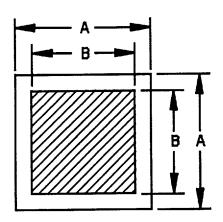
# DESIGN DATA

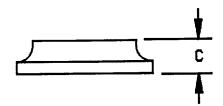
# Metallization:

Aluminum Top: (Cathode) . . . . . Back (Anode) . . . . . . Gold

- Dimensions are in inches.
   Metric equivalents are given for general information only.

FIGURE 3. Physical dimensions for JANHCA and JANKCA (die).





	Dimension					
Symbol	Inch	ies	Millimeters			
	Min	Max	Min	Max		
A	0.030	0.036	0.813	0.914		
В	0.022	0.027	0.584	0.686		
С	0.006	0.012	0.152	0.305		

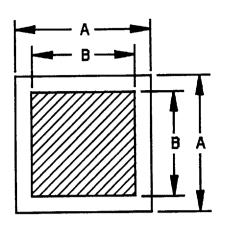
#### DESIGN DATA

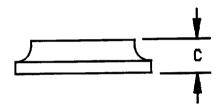
# Metallization:

Top: (Cathode) . . . . . Aluminum Back (Anode) . . . . . . Silver

- 1. Dimensions are in inches.
- 2. Metric equivalents are given for general information only.

FIGURE 4. Physical dimensions for JANHCB and JANKCB (die).





	Dimension					
Symbol	Inch	ies	Millimeters			
	Min	Max Min		Max		
A	0.030	0.036	0.813	0.914		
В	0.022	0.027	0.584	0.686		
С	0.006	0.012	0.152	0.305		

#### DESIGN DATA

Metallization:

Top: (Cathode) . . . . . Back (Anode) . . . . . . Silver Silver

#### NOTES:

Dimensions are in inches.
 Metric equivalents are given for general information only.

FIGURE 5. Physical dimensions for JANHCC and JANKCC (die).

#### 2. APPLICABLE DOCUMENTS

#### 2.1 Government documents.

2.1.1 <u>Specifications, standards, and handbooks</u>. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, cited in the solicitation (see 6.2).

#### SPECIFICATION

MILITARY

MIL-S-19500 - Semiconductor Devices, General Specification for.

STANDARD

MILITARY

MIL-STD-750 - Test Methods for Semiconductor Devices.

(Unless otherwise indicated, copies of federal and military specifications, standards, and handbooks are available from the Standardization Documents Order Desk, Building 4D, 700 Robbins Avenue, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this specification and the references cited herein, the text of this document shall take precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

#### 3. REQUIREMENTS

- 3.1 <u>Associated detail specification</u>. The individual item requirements shall be in accordance with MIL-S-19500, and as specified herein.
- 3.2 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein shall be as specified in MIL-S-19500, and as follows:

EC	Endcap.
US	Surface mount case outline, square endcap.

- 3.3 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-S-19500, and on figures 1, 2, and 3 herein.
- 3.3.1 <u>Construction except for JANHC an JANKC</u>. Devices shall be metallurgically bonded-thermally matched-noncavity-double plug construction in accordance with MIL-S-19500, 3.3.1.1, and 3.3.1.2 herein. The "US" version shall be structurally identical to the axial lead type except for lead configuration.
- 3.3.1.1 Metallurgical bond for diodes with  $V_Z > 6.8 \text{ V}$  dc. Category I metallurgical bonds as defined in MIL-S-19500 shall be utilized.
- 3.3.1.2 Metallurgical bond for diodes with  $V_Z \le 6.8 \text{ V}$  dc. Category I and category III bonds as defined in MIL-S-19500 may be utilized.
  - 3.4 Marking. Marking shall be in accordance with MIL-S-19500.
- 3.4.1 Marking of US version devices. For "US" version devices only, all marking (except polarity) may be omitted from the body, but shall be retained on the initial container.
- 3.4.2 <u>Polarity</u>. The polarity of all types shall be indicated with a contrasting color band to denote the cathode end. Alternatively, for US suffix devices, a minimum of three contrasting color dots spaced around the periphery on the cathode end may be used.

7

3.5 Selection of tighter tolerance devices. The C and D suffix devices shall be selected from JAN, JANTX, JANTXV, or JANS devices, which have successfully completed all applicable screening, and groups A, B, and C testing as 5 percent tolerance devices. All sublots of C and D suffix devices shall pass group A, subgroup 2, at tighter tolerances. Tighter tolerances for mounting clip temperature shall be maintained for reference purpose to establish correlation. For C and D tolerance levels,  $T_L = 25^{\circ}\text{C} \pm 2^{\circ}\text{C}$  at 0.375 from body or equivalent.

# 4. QUALITY ASSURANCE PROVISIONS

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection shall be in accordance with MIL-S-19500, and as specified herein. Lot accumulation period shall be 6 months in lieu of 6 weeks. This applies to JAN, JANTX and JANTXV quality levels only.
- 4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-S-19500, and as specified herein.
- 4.2.1 Group E inspection. Group E inspection shall be conducted in accordance with MIL-S-19500 and table II herein.
- 4.2.2 JANHC and JANKC devices. Qualification for JANC devices shall be as specified in appendix H of MIL-S-19500.
- 4.3 <u>Screening (all levels)</u>. Screening shall be in accordance with table II of MIL-S-19500, and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.
  - 4.3.1 Screening (JANHC and JANKC). Screening of die shall be in accordance with MIL-S-19500, appendix H.

Screen (see table	Measurements		
II of MIL-S-19500)	JANS level	JANTX and JANTXV levels	
1/	Thermal impedance, see 4.5.4	Thermal impedance, see 4.5.4	
7	Hermetic seal, gross leak	Hermetic seal, gross leak	
9	I <sub>R1</sub> and VZ (1N4465 thru 1N4496 only)	Not applicable	
11	$I_{R1}$ and $V_Z$ (1N4465 thru 1N4496 only); $\Delta I_{R1} \leq \pm 100$ percent of initial reading or 50 nA dc, whichever is greater. $\Delta V_Z \leq \pm 2$ percent of initial reading.	I <sub>R1</sub> and V <sub>Z</sub> (1N4465 thru 1N4496 only)	
12	See 4.3.2	See 4.3.2	
13 <u>2</u> / <u>3</u> /	Subgroups 2 and 3 of table I herein; ΔI <sub>RI</sub> (max) ≤ ±100 percent of initial reading or 50 nA, whichever is greater; ΔV <sub>Z</sub> ≤ ±2 percent of initial reading.	Subgroup 2 of table I herein; $\Delta I_{R1}(max) \leq \pm 100$ percent initial reading or 50 nA, whichever is greater; $\Delta V_z \leq \pm 2$ percent of initial reading.	

<sup>1/</sup> This test shall be performed anytime after screen 3.

Thermal impedance not applicable, if already performed 100%.
 Delta limits applicable to 1N4465 thru 1N4496 only.

# 4.3.2 Power burn-in conditions. Power burn-in conditions are as follows:

The diode shall be suspended by its leads (nonsurface mount only) with the mounting clips at a minimum of .375 inch (9.52 mm) from the device body in a room ambient as defined in (see 4.5) general requirements of MIL-STD-750. The test current  $I_z$  shall be adjusted to produce a junction temperature of +175°C maximum and  $I_z$  minimum shall be equal to 50 percent of column 8 of table III. For surface mount devices, the mounting clips shall contact the endcaps and the ambient temperature may be elevated in order to achieve the specified junction temperature.

- 4.4 <u>Quality conformance inspection</u>. Quality conformance inspection shall be in accordance with MIL-S-19500 and as specified herein. Group A inspection shall be performed on each sublot.
- 4.4.1 <u>Group A inspection</u>. Group A inspection shall be in accordance with MIL-S-19500 and table I herein. Thermal impedance conditions are as follows:

a.	$I_{M}$ measurement current	1 mA to 10 mA.
ь.	$I_{\text{H}}$ forward heating current	3A to 10 A.
c.	$t_{\mbox{\scriptsize H}}$ heating time	10 ms.
d.	t <sub>MD</sub> measurement delay time	100 μs maximum.

The maximum limit for  $Z_{\Theta JX}$  under these test conditions are  $Z_{\Theta JX(max)} = 4.5$ °C/W for category I bonds and  $Z_{\Theta JX(max)} = 7.5$ °C/W for category III bonds (see 3.3.1.1 and 3.3.1.2).

4.4.2 <u>Group B inspection</u>. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in tables IVa and IVb of MIL-S-19500. Electrical measurements (end-points) shall be in accordance with the applicable inspections of table 1, group A, subgroup 2 herein except  $Z_{\Theta JX}$  need not to be performed. See subgroup conditions for delta limits when applicable.

# 4.4.2.1 Group B inspection, table IVa (JANS) of MIL-S-19500.

Subgroup	Method	Condition
3	1056	25 cycles, condition A
3	1071	Test condition E NOTE: For non-transparent devices, hermetic seal may be performed after electrical measurements.
4	1037	$I_2$ = column 8 of table III at $T_A$ = room ambient as defined in the general requirements of paragraph 4.5 of MIL-STD-750; $t_{\rm on} = t_{\rm oil} = 3$ minutes minimum for 2,000 cycles. Mounting conditions in accordance with 4.5.2. No forced air cooling on the device shall be permitted. Leaded samples from this lot may be used in lieu of surface mount devices.
4	Endpoints:	$I_{\scriptscriptstyle R}$ endpoints in accordance with table III, column 13.
5	1027	$I_z$ = column 8 of table III for 96 hours; $P_T$ = 1.5 W; $T_A$ = +125°C or adjusted as required by the chosen $T_A$ to give an average lot $T_J$ = +275°C. Leaded samples from this lot may be used in lieu of surface mount devices.
5	Endpoints:	$I_{\text{R}}$ endpoints in accordance with table III, column 13.
6	3101 or 4081	$R_{\rm GJL}$ = 42°C/W maximum; $R_{\rm GJEC}$ = 20°C/W maximum; +25°C < $T_{\rm A}$ +35°C; reference temperature measuring point is the inside of mounting clip on lead or endcap (see 4.5.7).

# 4.4.2.2 Group B inspection, table IVb (JAN, JANTX and JANTXV of MIL-S-19500).

Subgroup	<u>Method</u>	Condition
1	2026	Immersion depth to within 0.10 inch (2.54 mm) of device body (leaded devices only).
2	4066	$I_{ZSM}$ = column 10 of table III at $T_A$ +25°C (see 4.5.1).
2	1071	Test condition E only NOTE: For non-transparent devices, hermetic seal may be performed after electrical measurements.
3	1027	$I_2(min)$ = 50 percent of column 8 of table III (conditions in accordance with 4.3.2); $I_A$ = room ambient as defined in the general requirements of paragraph 4.5 of MIL-STD-750.
3	Endpoints:	$I_{\mathrm{R}}$ endpoints in accordance with table III, column 13.

<sup>4.4.3 &</sup>lt;u>Group C inspection</u>. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in table V of MIL-S-19500 and herein. Electrical measurements (end-points) shall be in accordance with the applicable inspections of table I, group A, subgroup 2 herein except  $Z_{\text{BJX}}$  need not to be performed. See subgroup conditions for delta limits when applicable.

# 4.4.3.1 Group C inspection, table V of MIL-S-19500.

Subgroup	Method	Condition
2	2036	Tension - test condition A; 10 lbs; $t = 15 \text{ s} \pm 3 \text{ s}$ . Lead fatigue - Test condition E. NOTE: Not applicable to US versions.
2	1071	Test condition E only NOTE: For non-transparent devices, hermetic seal may be performed after electrical measurements.
6	1027	$I_Z(min)$ = 50 percent of column 8 of table III (conditions in accordance with 4.3.2); $I_A$ = room ambient as defined in the general requirements of paragraph 4.5 of MIL-SID-750.
6	Endpoints:	$I_{R}$ endpoints in accordance with table III, column 13.
7	4071	Temperature coefficient for JAN, JANTX and JANTXV only; $I_z$ = column 5 of table III; $T_{A1}$ = +25°C ±5°C; $T_{A2}$ = +100°C ±5°C; limit = column 14 of table III (see paragraph 4.5.3).
8	1056	Liquid N $_2$ (-195°C) to +150°C fluoro bath. The DUT shall be stabilized at the temperature extremes for 20 s minimum, transfer time $\leq$ 5 s, continuously monitor for discontinuities during the last five cycles, V $_1$ = 200 mA dc; 20 cycles for group C.
8	•••	Visual inspection - cracks in package shall be cause for rejection.
8	Endpoints:	$\Delta V_{\rm p}$ at 200 mA = ±20 mV or 2 percent of initial readings, whichever 1s greater.

<sup>4.5 &</sup>lt;u>Methods of examination and test</u>. Methods of examination and test shall be as specified in the appropriate tables and as follows.

- 4.5.1 Surge current ( $I_{ZSM}$ ). The peak currents specified in column 10 of table III shall be applied in the reverse direction and shall be superimposed on the current ( $I_z$  = column 5 of table III) a total of five surges at 1 minute intervals. Each individual surge shall be at one-half square wave pulse of 8.3 millisecond duration or an equivalent sine wave with the same effective (rms) current.
- 4.5.2 Voltage regulation ( $V_Z$  (reg)). A current of 10 percent of  $I_Z$  (column 8) shall be maintained until thermal equilibrium is attained and the  $V_Z$  shall be noted. The current shall then be increased to a level of 50 percent of  $I_Z$  (column 8) and maintained at this level until thermal equilibrium is attained at which time the voltage change shall not exceed column 9 of table III. For this test, the diode shall be suspended by its leads (nonsurface mount) with mounting clips whose inside edge is located at 0.375  $\pm$ 0.010 inch (9.52  $\pm$ 0.25 mm) from the body and the lead temperature at inside edge of the mounting clips shall be maintained at a temperature between  $\pm$ 23°C and  $\pm$ 33°C. For surface mount packages, the diode shall be suspended by the endcaps with the temperature of the endcaps being maintained between  $\pm$ 23°C and  $\pm$ 33°C. For JANC, the die shall be stabilized at  $\pm$ 25°C and the test shall be performed utilizing pulse condition. This measurement may be performed after a shorter time interval following application of the test current than that which provides thermal equilibrium if correlation can be established to the satisfaction of the qualifying activity.
- 4.5.3 Temperature coefficient of regulator voltage ( $\alpha_{VZ}$ ). The device shall be temperature stabilized with current applied prior to reading regulator voltage at the specified ambient temperature. For JANC, this test shall be made with the chip resting on a metal heat sink maintained at +25°C ±3°C, utilizing pulse condition.
- 4.5.4 Thermal impedance ( $Z_{\Theta JX}$  measurements). The  $Z_{\Theta JX}$  measurements shall be performed in accordance with MIL-STD-750, method 3101. The maximum limit shall not to exceed the Group A, Subgroup 2 limit for  $Z_{\Theta JX}$  in screening (table II of MIL-S-19500).
- 4.5.4.1 Thermal impedance ( $Z_{\Theta JX}$  measurements) for initial qualification or requalification. The  $Z_{\Theta JX}$  measurements shall be performed in accordance with MIL-STD-750, method 3101 (read and record date  $Z_{\Theta JX}$ ).  $Z_{\Theta JX}$  shall be supplied on one lot (500 devices minimum and a thermal response curve shall be submitted). Twenty two of these samples shall be serialized and provided to the qualifying activity for correlation prior to shipment of parts. Measurements conditions shall be in accordance with 4.4.1.
- 4.5.5 Regulator voltage. The test current (column 5 of table III) shall be applied until thermal equilibrium is attained prior to reading the regulator voltage. For this test, the diode shall be suspended by its leads (nonsurface mount) with mounting clips whose inside edge is located at 0.375 ±0.010 inch (9.52 ±0.25 mm) from the body and the lead temperature at inside edge of the mounting clips shall be maintained at a temperature of +23°C to +33°C. For surface mount diodes, the diode shall be suspended by the endcaps with the temperature of the endcaps being maintained at +23°C to +33°C. For JANC, this measurement shall be made with the chip resting on a metal heat sink maintained at +25°C ±3°C. This measurement may be performed after a shorter time following application of the test current than that which provides thermal equilibrium if correlation to stabilized readings can be established to the satisfaction of the qualifying activity.
- 4.5.6 <u>Pulse measurements</u>. Conditions for pulse measurements shall be as specified in paragraph 4.3.2.1 of MIL-SID-750.

TABLE I. Group A inspection.

Inspection 1/	MIL-STD-750		Symbol	Lim	<u>2</u> / Limits	
•	Method	Conditions		Min	Max	
Subgroup 1						
Visual and mechanical examination	2071					
Subgroup 2						
Thermal impedance <u>4</u> /	3101	Category I bond Category III bond (See 4.4.1)	S <sup>enx</sup>		4.5 7.5	°C/W
Forward voltage	4011	I <sub>F</sub> = 200 mA dc	V <sub>F1</sub>		1.0	V dc
Forward voltage	4011	I <sub>F</sub> = 1 A dc	V <sub>F2</sub>		1.5	V dc
Reverse current leakage	4016	DC method; V <sub>R</sub> = column 11 of table III	IRI		Column 12	μA do
Regulator voltage <u>3</u> /	4022	$I_z$ = column 5 of table III (see 4.5.5)	Vz	Column 3 -5, -2, -1 percent	Column 4 +5, +2, +1 percent	V dc
Subgroup 3					,	
High temperature operation		T <sub>A</sub> = +150°C				
Reverse current leakage	4016	DC method; V <sub>R</sub> = column 11 of table III	182		Column 16	μA di
Subgroup 4						
Small-signal reverse breakdown impedance	4051	$I_z$ = column 5 of table III $I_{mg}$ = 10 percent $I_z$	Z <sub>z</sub>		Column 6	Ω
Knee impedance	4051	$I_{ZK}$ = column 15 of table III $I_{mg}$ = 10 percent $I_{ZK}$	Z <sub>ZK</sub>		Column 7	Ω
Subgroup 5						
Not applicable						
Subgroup 6						
Surge current	4066	JANS only I <sub>zsm</sub> = column 10 of table III (see 4.5.1)	Izsm			
End-point electrical measurements		See table I, group A, subgroup 2 except Z <sub>eJx</sub>				

See footnotes at end of table.

TABLE 1. Group A inspection - Continued.

Inspection 1/		MIL-STD-750	Symbol	L	Unit	
	Method	Conditions		Min	Max	<u> </u>
Subgroup 7  Voltage regulation 3/  Temperature coefficient of regulator voltage	4071	See 4.5.2  JANS level only $I_Z = \text{column 5 of table III}$ $T_{A1} = +25^{\circ}\text{C} \pm 5^{\circ}\text{C},$ $T_{A2} = 120^{\circ}\text{C} \le T_2 \le 130^{\circ}\text{C}$	V <sub>Z(reg)</sub> α <sub>VZ</sub>		Cotumn 9 Column 14	V dc %/°C

<sup>1/</sup> For sampling plan, see MIL-S-19500. 2/ Column references are to table III. 3/ For JANC, test using pulse conditions. 4/ Not require for JANHC and JANKC

TABLE II. Group E inspection (all quality levels).

Inspection		Sampling	
	Method	Conditions	plan
Subgroup 1			22 devices c = 0
Temperature cycling	1051	500 cycles	
Electrical measurements		See table I, group A, subgroup 2	
Subgroup 2			22 devices c = 0
Steady-state intermittent operating life	1037	$I_z$ = $I_{22}$ (column 8 of table III) at $T_A$ = +25°C; $T_{on}$ = $T_{off}$ = 3 minutes minimum for 10,000 cycles. No forced air cooling on the device shall be permitted. (Mounting conditions in accordance with 4.5.2.)	
Electrical measurements		See table I, group A, subgroup 2	
Subgroup 3			22 devices c = 0
Not applicable			
Subgroup 4			
Thermal resistance (see 4.5.7)	3101 or 4081	$R_{\Theta JL} = 42$ °C/W (max) at L = 3/8"; $R_{\Theta JEC} = 20$ °C/W max for US types,	

TABLE III. <u>Electrical characteristics and test conditions (all case outlines)</u>.

Col 1	Col 2	Col 3	Col	Col 5	Col 6	Col 7	Col 8	Col 9	Col 10	Col 11	Col 12	Col 13	Col 14	Col 15	Col 16
Device type	V <sub>z</sub> Nom	V <sub>z</sub> Min <u>1</u> / <u>2</u> /	V <sub>z</sub> Max	I <sub>z</sub> test   current   T <sub>A</sub>  = +25°C	Zz	Z <sub>K</sub> Knee imped- ance	I <sub>z</sub> Max dc current T <sub>A</sub> = +25°C	V <sub>z</sub> (reg) voltage regula- tion <u>3</u> /	I <sub>ZSM</sub> T <sub>A</sub> = +25°C 4/	voltage	I <sub>R</sub> Reverse current dc I <sub>R1</sub>	I <sub>R</sub> Reverse current dc, I <sub>R1</sub> post test	ature	I <sub>zk</sub> Test current	I <sub>R</sub> Reverse current dc T <sub>A</sub> = +150°C
	v	v	v	mA	Ω	Ω	mA	v	Α	V	μΑ	μΑ	%/°C	mA	μΑ
1N6485 1N6486 1N6487 1N6488 1N6489	3.3 3.6 3.9 4.3 4.7	3.14 3.42 3.71 4.09 4.47	3.46 3.78 4.09 4.51 4.93	76 69 64 58 53	10 10 9 9 8	400 400 400 400 500	433 397 366 332 304	0.9 0.8 .75 .70 .60	4.2 3.9 3.6 3.3 3.0	1.0 1.0 1.0 1.0 1.0	50.00 50.00 35.00 5.00 4.00	75.00 75.00 50.00 7.50 6.00	075 070 060 +.050 ±.025	1.00 1.00 1.00 1.00 1.00	500 200 100 100 100
1N6491 1N4460 1N4461 1N4462	5.6 6.2 6.8 7.5	5.32	5.88 6.51 7.14 7.87	45 40 37 34	5 4 2.5 2.5	600 200 200 400	255 230 210 191	.40 .35 .30 .35	2.5 2.3 2.1 1.9	2.0 3.72 4.08 4.50	0.50 10.00 5.00 1.00	1.00 20.00 10.00 2.00	±.040 +.050 +.057 +.061	1.00 1.00 1.00 0.50	100 50 20 10
1N4463 1N4464 1N4465 1N4466 1N4467	8.2 9.1 10 11 12		8.61 9.55 10.50 11.55 12.60	31 28 25 23 21	3.0 4.0 5.0 6.0 7.0	400 500 500 550 550	174 157 143 130 119	.40 .45 .50 .55	1.7 1.6 1.4 1.3 1.2	4.92 5.46 8.0 8.8 9.6	0.50 0.30 0.30 0.30 0.20	1.00 0.60 0.60 0.60 0.40	+.065 +.068 +.071 +.073 +.076	0.50 0.50 0.25 0.25 0.25	5 3 3 2 2
1N4468 1N4469 1N4470 1N4471 1N4472	13 15 16 18 20	12.35 14.25 15.20 17.10 19.00	13.65 15.75 16.80 18.90 21.00	19 17 15.5 14 12.5	8.0 9.0 10.0 11.0 12.0	550 600 600 650 650	110 95 90 79 71	.65 .75 .80 .83	1.1 .95 .90 .79	10.4 12.0 12.8 14.4 16.0	0.05 0.05 0.05 0.05 0.05	0.10 0.10 0.10 0.10 0.10	+.079 +.082 +.083 +.085 +.086	0.25 0.25 0.25 0.25 0.25	2 2 2 2 2
1N4473 1N4474 1N4475 1N4476 1N4477	22 24 27 30 33	20.90 22.80 25.70 28.50 31.40	23.10 25.20 28.30 31.50 34.60	11.5 10.5 9.5 8.5 7.5	14 16 18 20 25	650 700 700 750 800	65 60 53 48 43	1.0 1.1 1.3 1.4 1.5	.65 .60 .53 .48	17.6 19.2 21.6 24.0 26.4	0.05 0.05 0.05 0.05 0.05	0.10 0.10 0.10 0.10 0.10	+.087 +.088 +.090 +.091 +.092	0.25 0.25 0.25 0.25 0.25	2 2 2 2 2

See footnotes at end of table.

TABLE III. Electrical characteristics and test conditions (all case outlines) - Continued.

Col 1	Col 2	Col 3	Col 4	Col 5	Col 6	Col 7	Col 8	Col 9	Col 10	Col 11	Col 12	Col 13	Col 14	Col 15	Col 16
Device type	V <sub>Z</sub> Nom	V <sub>z</sub> Min <u>1</u> / <u>2</u> /	V <sub>z</sub> Max <u>1</u> / <u>2</u> /	I <sub>z</sub> test  current T <sub>A</sub> = +25°C	Z <sub>2</sub> Imped- ance	Z <sub>K</sub> Knee imped- ance	I <sub>Z</sub> Max dc current T <sub>A</sub> = +25°C	tion		V <sub>R</sub> Reverse voltage		current		I <sub>ZK</sub> Test current	I <sub>R</sub> Reverse current dc T <sub>A</sub> = +150°C I <sub>R2</sub>
	v	v	v	mA	Ω	Ω	mA_	V	Α	v	μA	μΑ	%/°C	mA	μΑ
1N4478 1N4479 1N4480 1N4481 1N4482 1N4483 1N4484 1N4486 1N4487 1N4488 1N4489 1N4490 1N4491 1N4492 1N4493 1N4493 1N4494 1N4495	110 120 130 150 160 180	34.2 37.1 40.9 44.7 48.5 53.2 58.9 64.6 71.3 77.9 86.5 95.0 104.5 114.0 123.5	37.8 40.9 45.1 49.3 53.5 58.8 65.1 71.4 78.7 86.1 95.5 105.0 115.5 126.0 136.5	7.0 6.5 6.0 5.5 5.0 4.5 4.0 3.7 3.3 3.0 2.8 2.5 2.3 2.0 1.9	27 30 40 50 60 70 80 100 130 160 250 300 400 500 700 11300 11500	850 900 950 1000 1100 1300 1500 1700 2000 2500 3000 3100 4000 4500 5000 6500 7000 8000	40 37 33 30 28 26 23 21 19 17 16 14 13 12 11	8.0 10.0	.40 .37 .33 .30 .28 .26 .23 .21 .19 .17 .16 .14 .13 .12 .11	28.8 31.2 34.4 37.6 40.8 44.8 49.6 54.4 60.0 65.6 72.8 80.0 88.0 96.0 104	.05 .05 .05 .05 .05 .25 .25 .25 .25 .25 .25 .25 .25 .25	.10 .10 .10 .10 .10 .25 .25 .25 .25 .25 .25 .25 .25 .25 .25	+.093 +.094 +.095 +.095 +.096 +.097 +.097 +.098 +.098 +.099 +.100 +.100 +.100 +.100 +.100 +.100 +.100	0.25 0.25 0.25 0.25 0.25 0.25 0.25 0.25	2 2 2 2 2 2 2 10 10 10 10 10 10 10 10 10 10 10

<sup>1/</sup> See 4.5.5. Voltages shown are for 5 percent tolerance devices. Voltages for 2 and 1 percent tolerances devices shall be calculated accordingly.

<sup>2/ 1</sup>N4460D through 1N4496D and 1N6485D through 1N6491D are 1 percent voltage tolerance.
1N4460C through 1N4496C and 1N6485C through 1N6491C are 2 percent voltage tolerance.
1N4460 through 1N4496 and 1N6485 through 1N6491 are 5 percent voltage tolerance.

<sup>3/</sup> See 4.5.2.

<sup>&</sup>lt;u>4</u>/ See 4.5.1.

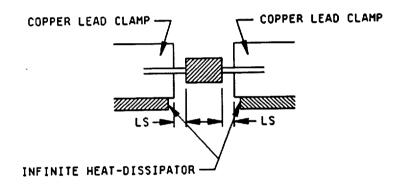
<sup>5</sup>/ See 4.5.3.

4.5.7 <u>Thermal resistance</u>. Thermal resistance measurements shall be conducted in accordance with test method 3101 of MIL-STD-750. The following details shall apply:

 $I_H$  = 2.0 A dc minimum  $I_M$  = 1 to 10 mA  $t_{MD}$  = 100  $\mu$ s maximum  $t_{\nu}$  = thermal equilibrium

The device shall be allowed to reach thermal equilibrium at current  $I_{H}$  before the measurement shall be made.

Lead spacing: LS = 3/8 inches for leaded devices. LS = 0 (endcap mount) for US devices.



# FIGURE 4. Mounting arrangement.

- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-S-19500.
- 6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Notes. The notes specified in MIL-S-19500 are applicable to this specification.

- 6.2 <u>Acquisition requirements</u>. Acquisition documents must specify the following:
  - a. Issue of DODISS to be cited in the solicitation.
  - b. Lead finish as specified.
  - c. Product assurance level, type designator, and for die acquisition, the JANHC and JANKC identification (see figure 3 and 6.3), top and bottom metallization.
- 6.3 <u>Suppliers of die.</u> The qualified die suppliers with the applicable letter version (example JANHCA1N4461) will be identified on the QPL.

	JANC ordering informati Manufactur	
PIN	12969	••
N4461	JANHCA1N4461	
thru	thru	
IN4496	JANHCA1N4496	
1N4461	JANHCB1N4461	
thru	thru	
1N4496	JANHCB1N4496	
1N4461	JANHCC1N4461	
thru	thru	
1N4496	JANHCC1N4496	

6.4 Changes from previous issue. Marginal notations are not used in this revision to identify changes with respect to the previous issue due to the extensiveness of the changes.

# CONCLUDING MATERIAL

Custodians:

Army - ER

Navy - EC

Air Force - 17

NASA - NA

Review activities:

Army - AR, MI, SM Navy - AS, CG, MC Air Force - 13, 19, 85

Preparing activity: DLA - ES

(Project 5961-1544)